

# BRGB15N65FL

Rev.A Sep.-2023

## / Descriptions

TO-220FL

Insulated-Gate Bipolar Transistor in a TO-220FL Plastic Package

## / Features

650V/15A  $V_{CE(SAT)} = 1.60V(\text{typ.}) @ I_C = 15A$

Fast Switching

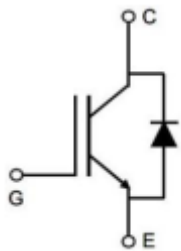
$V_{CE(SAT)}$  Low  $V_{CE(SAT)}$

HF Product.

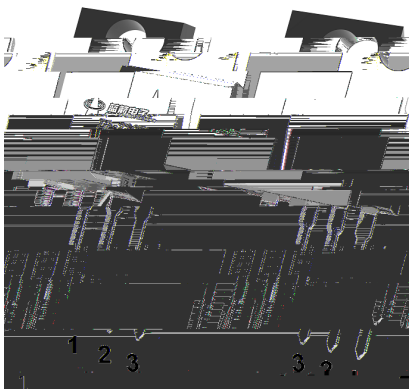
## / Applications

Motor Drives, OBC, PTC.

## / Equivalent Circuit



## / Pinning



PIN1 G

PIN 2 C

PIN 3 E

## / Marking

See Marking Instructions.

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DATA SHEET

| Parameter                    |            | Symbol    | Rating   | Unit |
|------------------------------|------------|-----------|----------|------|
| Collector-Emitter Voltage    |            | $V_{CES}$ | 650      | V    |
| Gate-Emitter Voltage         |            | $V_{GES}$ | $\pm 30$ | V    |
| Continuous Collector Current | $T_C=+25$  | $I_C$     | 30       | A    |
|                              | $T_C=+100$ |           | 15       | A    |

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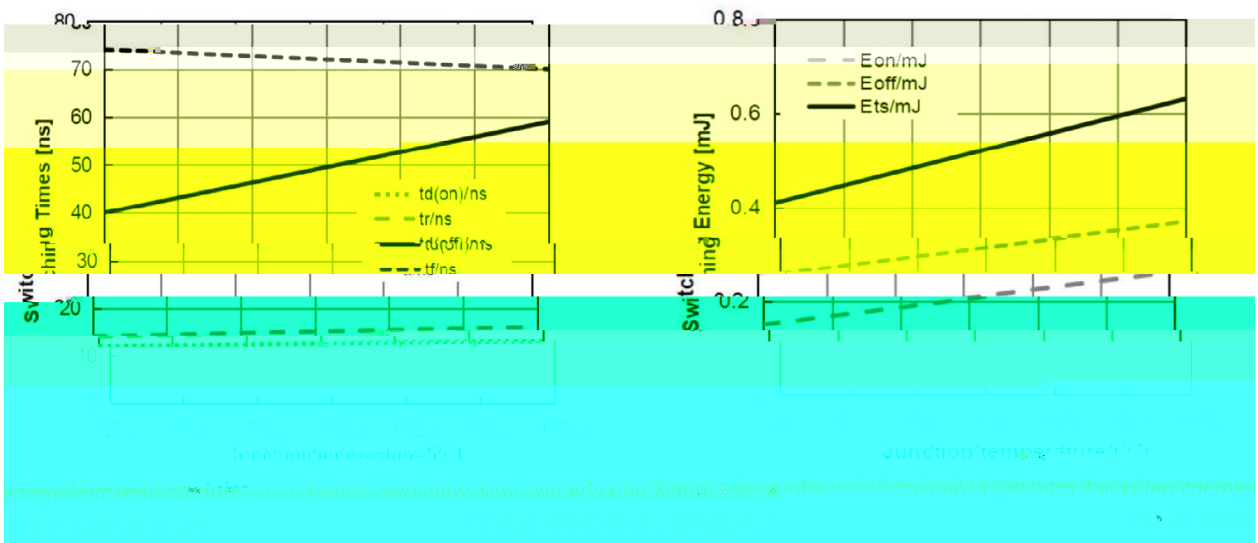
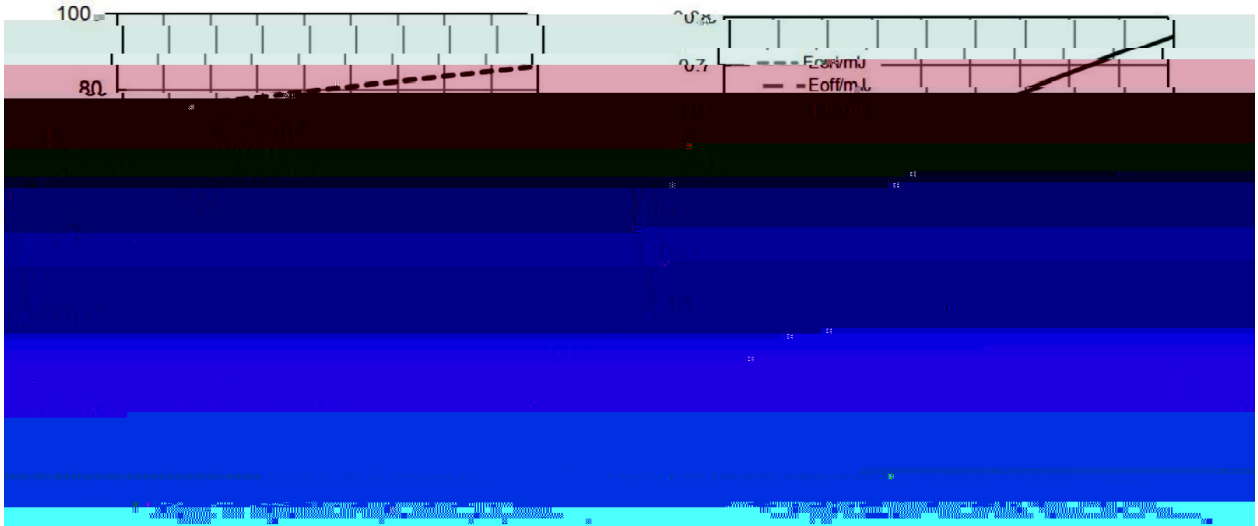
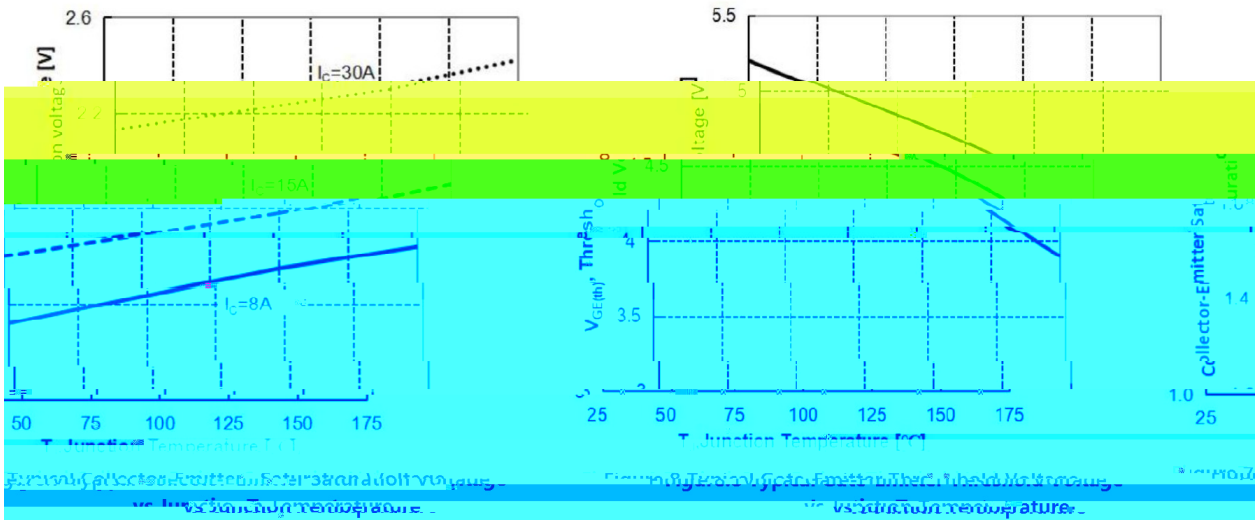


DATA SHEET

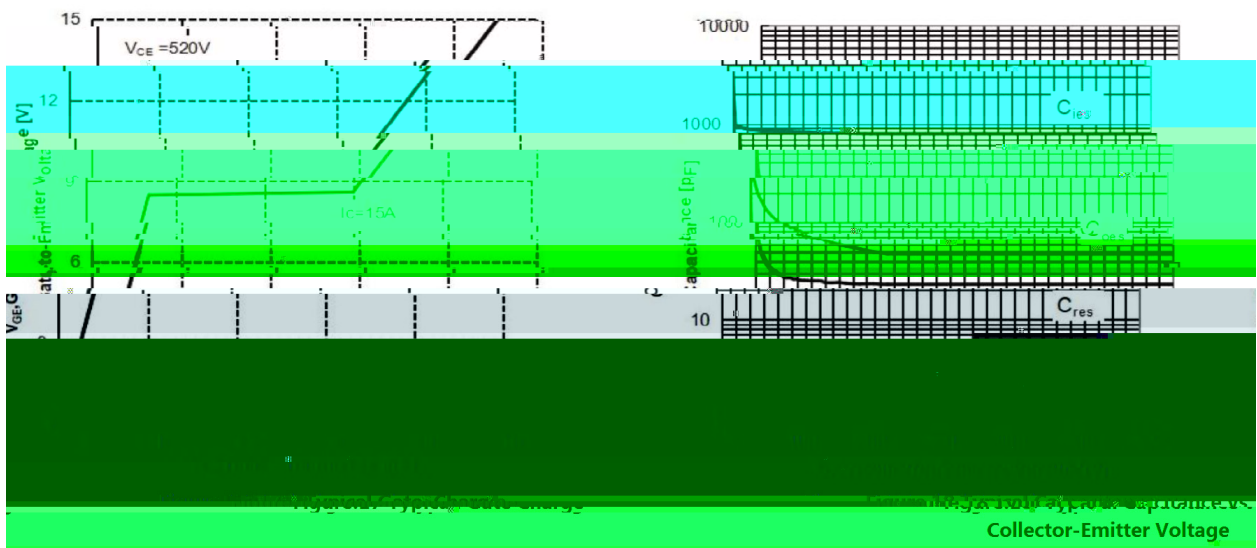
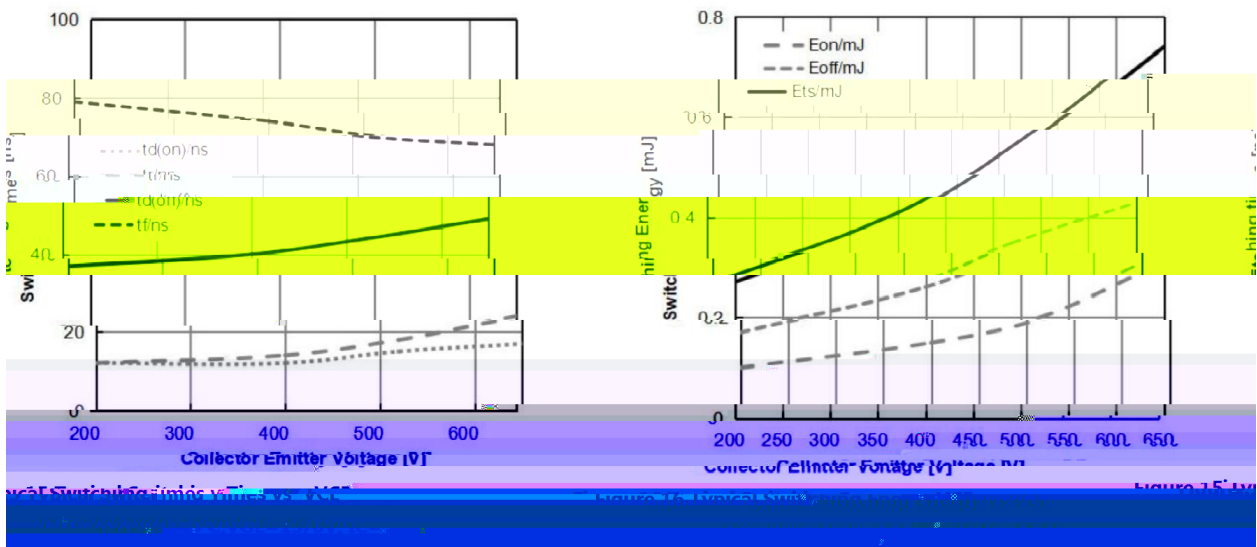
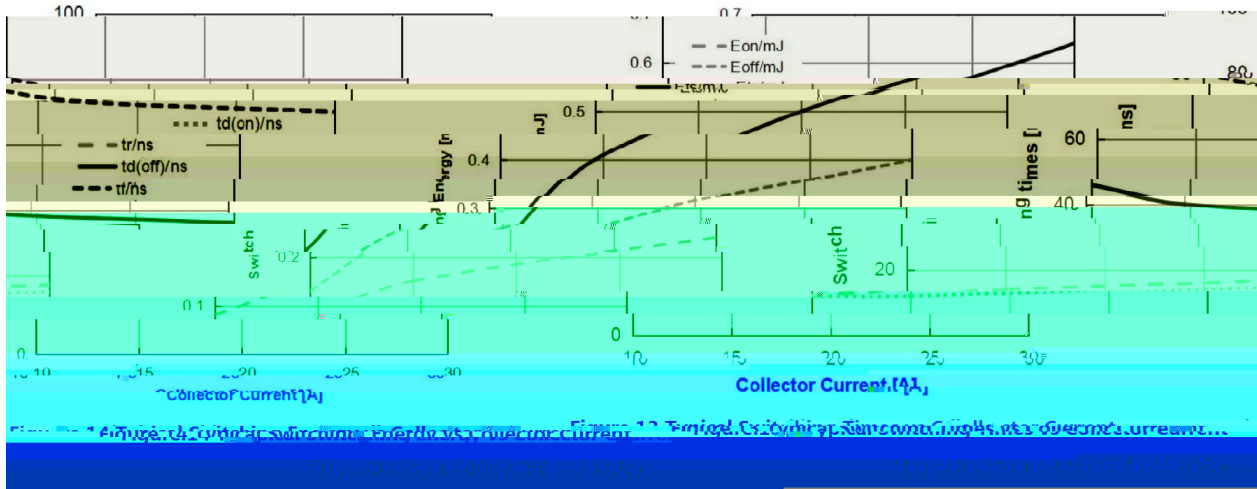
| Parameter                    | Symbol       | Test Conditions  | Min | Typ  | Max | Unit |
|------------------------------|--------------|--|-----|------|-----|------|
| Input Capacitance            | $C_{ies}$    | $V_{GE}=0V, V_{CE}=25V,$<br>$f=1MHz$   |     | 791  |     | pF   |
| Output Capacitance           | $C_{oes}$    |  |     | 130  |     | pF   |
| Reverse Transfer Capacitance | $C_{res}$    |  |     | 33   |     | pF   |
| Total Gate Charge            | $Q_g$        | $V_{GE}=15V, V_{CC}=520V,$<br>$I_C=15A$  |     | 45   |     | nC   |
| Gate to Emitter Charge       | $Q_{ge}$     |  |     | 7    |     | nC   |
| Gate to Collector Charge     | $Q_{gc}$     |  |     | 23   |     | nC   |
| Turn-On Delay Time           | $t_{d(on)}$  | $T_J=25$ ,<br>$V_{GE}=15V, V_{CC}=400V,$<br>$I_C=15A, R_G=5$<br>Inductive Load |     | 12   |     | ns   |
| Turn-On Rise Time            | $t_r$        |  |     | 14   |     | ns   |
| Turn-Off Delay Time          | $t_{d(off)}$ |  |     | 40   |     | ns   |
| Turn-Off Fall Time           | $t_f$        |  |     | 74   |     | ns   |
| Turn-On Energy               | $E_{on}$     |  |     | 0.15 |     | mJ   |
| Turn-Off Energy              | $E_{off}$    |  |     | 0.26 |     | mJ   |
| Total Switching Energy       | $E_{ts}$     |  |     |      |     |      |



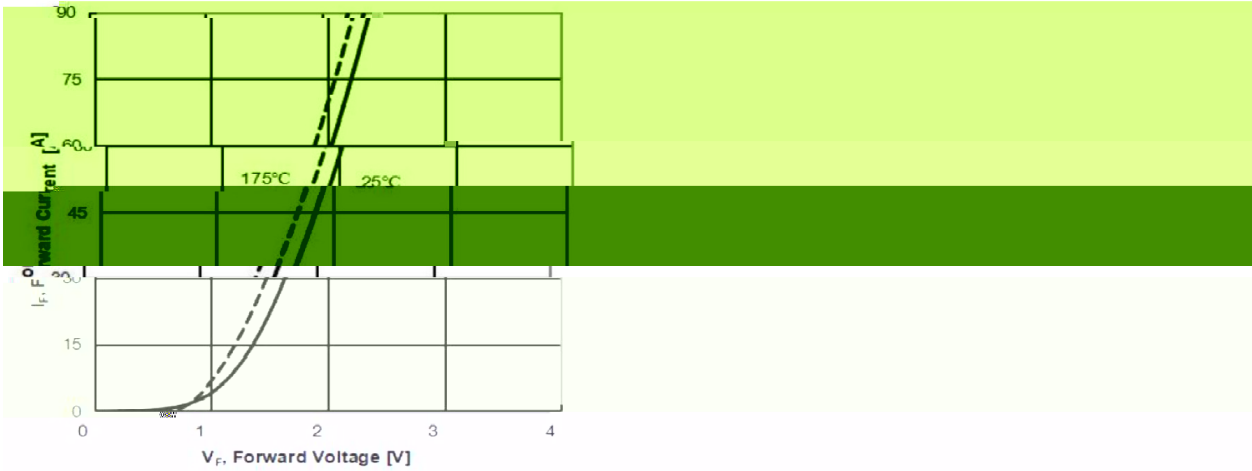
**/ Electrical Characteristic Curve**



**/ Electrical Characteristic Curve**

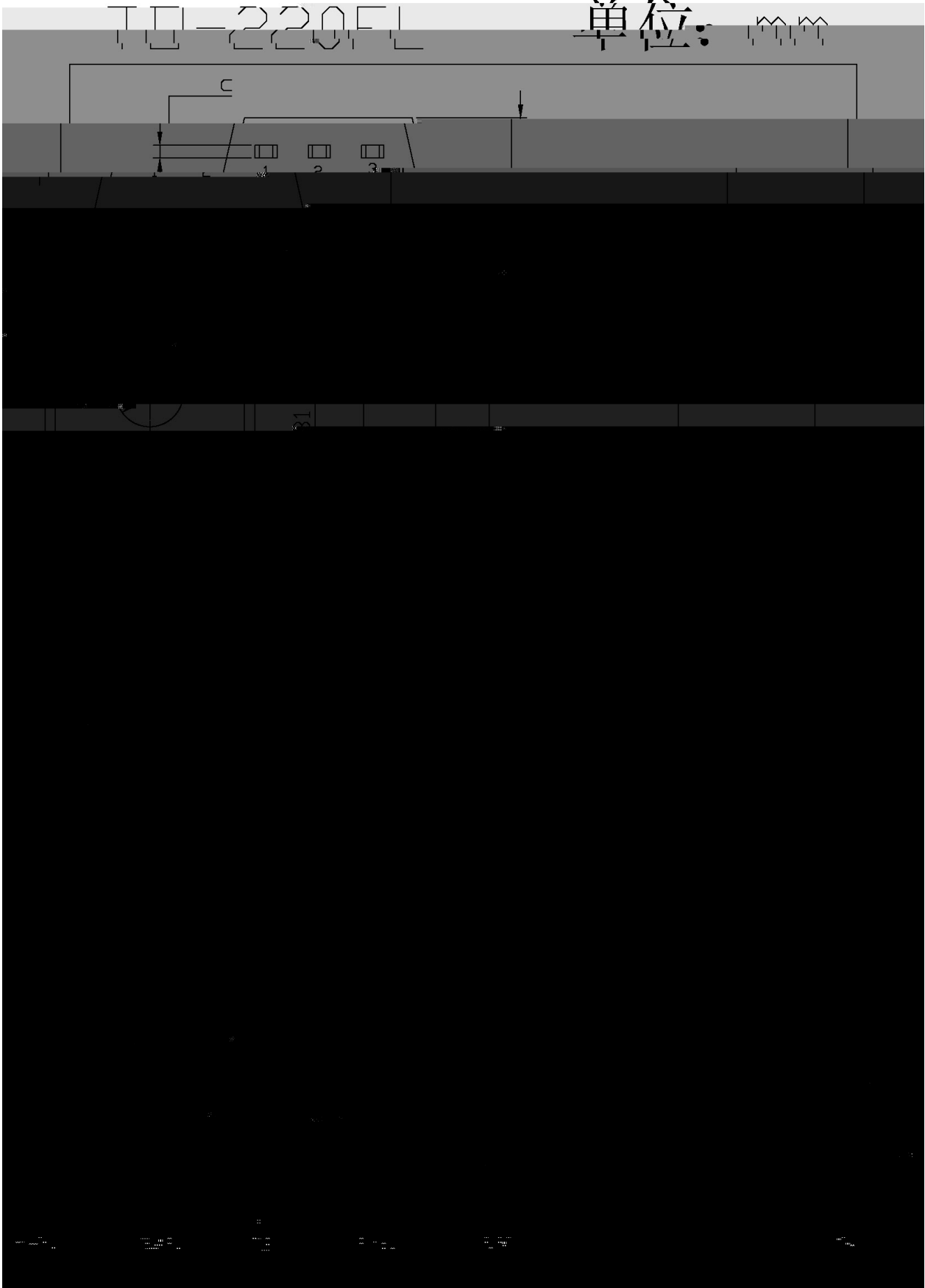


**/ Electrical Characteristic Curve**

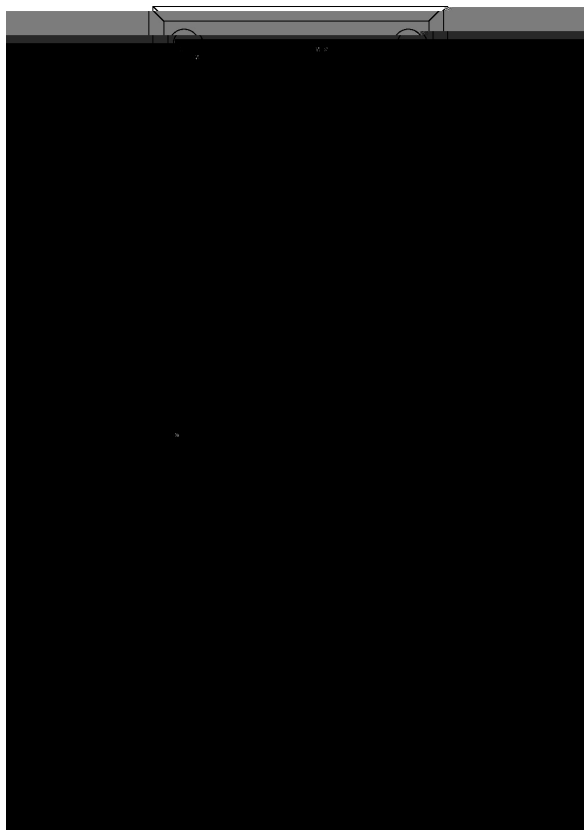


Typical Diode Forward Current vs Forward Voltage. Figure.19

**/ Package Dimensions**



**/ Marking Instructions**



BR

GB15N65

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Note:

BR: Company Code

GB15NN65: Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No



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( ) / Temperature Profile for Dip Soldering(Pb-Free)

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Note:

- 1      25 150      60 90sec;      1.Preheating:25~150 , Time:60~90sec.
- 2      255..5      5..0.5sec;      2.Peak Temp.:255..5 , Duration:5..0.5sec.
- 3      2 10 /sec.      3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

705..5 ǁ 10... (T)10769(e)147(m(..:70±55))TJ/T107 1 Tf5.05757 0 TD0 Tc0 Tw

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